# **FEATURES**

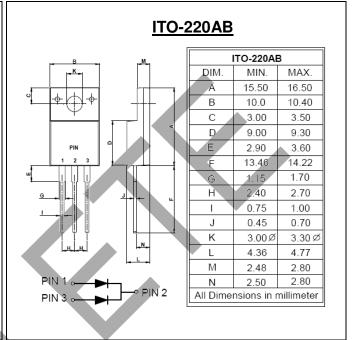
- Metal of silicon rectifier, majority carrier conduction
- · Guard ring for transient protection
- · Low power loss, high efficiency
- · High current capability, low VF
- · High surge capability
- · Plastic package has UL flammability classification
- For use in low voltage, high frequency inverters, free wheeling, and polarity protection applications
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)

# **MECHANICAL DATA**

· Package: ITO-220AB molded plastic · Polarity: As marked on the body · Weight: 0.06 ounces, 1.70 grams

· Mounting position: Any

• Max. mounting torque = 0.5 N.m (5.1 Kgf-cm)



# MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

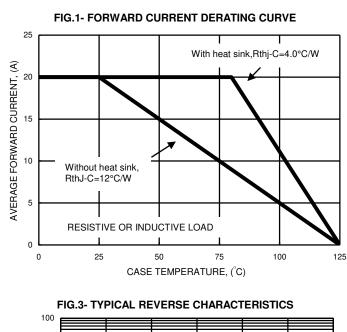
Ratings at 25°C ambient temperature unless otherwise specified.

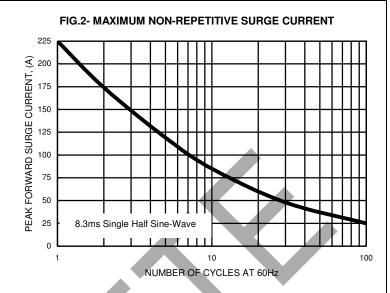
PARAMETER	SYMBOL	SBF2030CT	SBF2040CT	SBF2045CT	UNIT
Maximum Repetitive Peak Reverse Voltage	V <sub>RRM</sub>	30	40	45	V
Maximum RMS Voltage	V <sub>RMS</sub>	21	28	31.5	V
Maximum DC Blocking Voltage	V <sub>DC</sub>	30	40	45	V
Maximum Average Forward Rectified Current(See Fig.1)  @TC=80°C	I <sub>(AV)</sub>	20			Α
Peak Forward Surge Current 8.3ms single half sine-wave superimposed on rated load	I <sub>FSM</sub>	225			Α
Maximum Forward Voltage at 10A DC (Note 3)	V <sub>F</sub>	0.55			V
Maximum DC Reverse Current at Rated DC Blocking Voltage  @TJ=25°C @TJ=100°C	IR	0.4 60			mA
Typical Junction Capacitance per element (Note 4)	CJ	680		РF	
Typical thermal resistance _ Junction to Lead (Note 5)	Rejc	4.0		°C/W	
Operating junction temperature range	TJ	-55 to +125			°C
Storage temperature range	Tstg	-55 to +150			°C
Dielectric Strength from terminals to case, AC with t=1 minute, RH<30%	V <sub>dis</sub>	2000			V

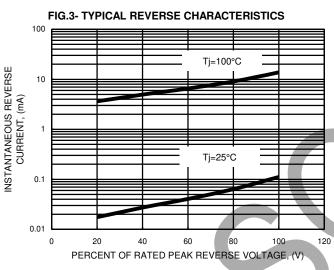
## Notes:

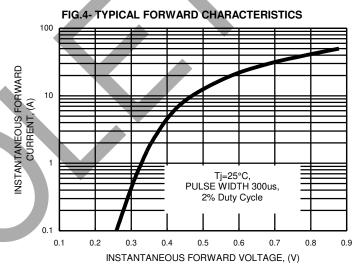
- 1. EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. All applicable RoHS exemptions applied.
- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. 300us Pulse Width, 2% Duty Cycle.
- 4. Measured at 1.0MHz and applied reverse voltage of 4.0 V DC.
- 5. Thermal Resistance Junction to Case, device mounted on L150xW150xH1.6mm\_copper heat sink.

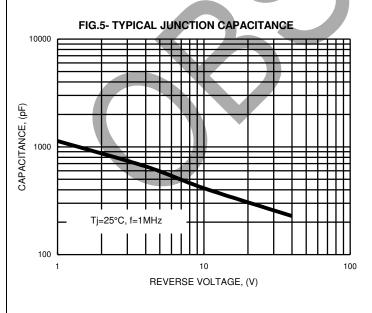
- PART DISCONTINUED

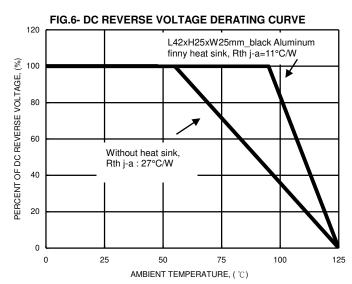










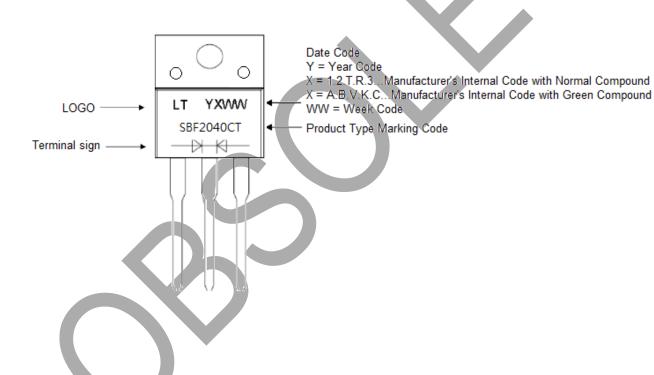




# **Ordering Information:**

Part Number	Package	Packing		
r art Number	Tuonage	Qty.	Carrier	
SBF2040CT	ITO-220AB	50pcs	Tube	

# **Marking Information:**



# **OBSOLETE - PART DISCONTINUED**

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